Transistors

Digital transistors (built-in resistor) DTC143TE / DTC143TUA / DTC143TKA DTC143TSA

ROHA

Features

 Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).

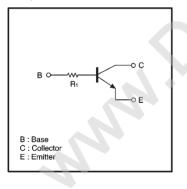
2) The bias resistors consist of thinfilm resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.

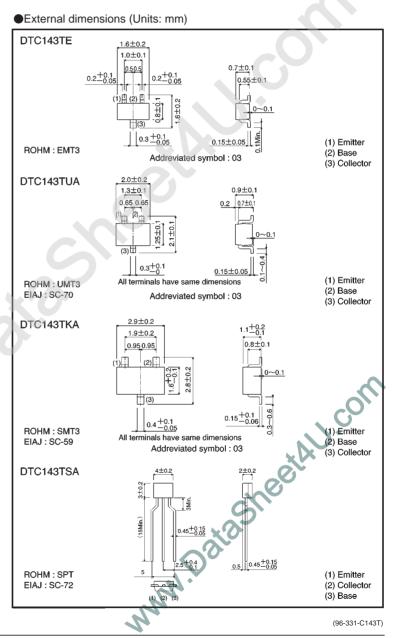
 Only the on/off conditions need to be set for operation, making device design easy.

Structure

PNP digital transistor (Built-in resistor type)

Equivalent circuit





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•Absolute maximum ratings (Ta = 25° C)

Parameter	Symbol	Limits (DTC143T				Unit
Parameter		E	UA	KA	SA	Unit
Collector-base voltage	Vсво	50				V
Collector-emitter voltage	VCEO	50				V
Emitter-base voltage	Vebo	5				V
Collector current	lc	100			mA	
Collector power dissipation	Pc	150	20	00	300	mW
Junction temperature	Tj	150			Ĵ	
Storage temperature	Tstg	-55~+150			Ĉ	

•Electrical characteristics (Ta = 25° C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВVсво	50	-	—	V	Ic=50 μ A
Collector-emitter breakdown voltage	BVCEO	50	-	-	V	Ic=1mA
Emitter-base breakdown voltage	BVEBO	5	—	—	V	Iε=50 μ A
Collector cutoff current	Ісво	_	-	0.5	μA	V _{CB} =50V
Emitter cutoff current	Іево	_	-	0.5	μA	VEB=4V
Collector-emitter saturation voltage	VCE(sat)	_	_	0.3	V	Ic/IB=5mA/0.25mA
DC current transfer ratio	hfe	100	250	600	_	VCE=5V, IC=1mA
Input resistance	Rı	3.29	4.7	6.11	kΩ	_
Transition frequency	fτ	-	250	—	MHz	Vce=10V, Ie=-5mA, f=100MHz *

* Transition frequency of mounted transistor

Packaging specifications

	Package	EMT3	UMT3	SMT3	SPT
	Packaging type	Taping	Taping	Taping	Taping
	Code	TL	T106	T146	TP
Part No.	Basic ordering unit (pieces)	3000	3000	3000	5000
DTC143TE		0	_	_	-
DTC143TU	A	-	0	_	_
DTC143TK	A	—	_	0	_
DTC143TS	A	-	_	_	0

Electrical characteristic curves

